# Selection Guide

## **HSI Series Modules**

- Single channel
- High bandwidth for dynamic signals
- Isolation (all models)
- Analog signal output (±5 V)
- Single channel modularity
- For DEWETRON systems with built-in DAQ rack
- Pure signal conditioning solution in conjunction with DEWE-30 series racks



Module	Input type	Ranges	TEDS	Bandwidth (BW), Filters (LP = lowpass, HP = highpass)	Isolation (ISO), Overvoltage protection (OP)	
Universal measurement						
HSI-STG  V	Strain gauge, bridge sensors Piezoresistive bridge Voltage Resistance Pt100, Pt200, Pt500, Pt1000, Pt2000 IEPE® via MSI-BR-ACC Thermocouple via MSI-BR-TH-> Charge via MSI-BR-CH-50	±0.1 to ±1000 mV/V (@ 5 VDC <sub>esc</sub> ) ±0.5 to 10000 mV/mA (@ 1 mA <sub>esc</sub> ) ±500 μV to ±10 V 25 mΩ to 100 kΩ -200° C to 850° C ±100 to ±10000 mV full range of TC type up to 50000 pC		BW: up to 2 MHz LP: 100 Hz to 2 MHz HP: 1 Hz	ISO: 350 V <sub>DC</sub> OP: ±50 V <sub>DC</sub>	
MSI MSI MSI High voltage measurement	Voltage via MSI-BR-V-200	up to ±200 V				
HSI-HV	High voltage	±20 to ±1400 V	-	BW: 2 MHz LP: 100 Hz to 2 MHz	ISO: 1.8 kV <sub>RMS</sub>	
Voltage & current measurement						
HSI-LV I	Voltage Current with external shunt IEPE® via MSI-V-ACC	±10 mV to ±50 V 20 mA / 5 A ±10 mV to 5 V	<b>√</b>	BW: 2 MHz LP: 100 Hz to 2 MHz	ISO: up to 1 kV <sub>RMS</sub> OP: 350 V <sub>DC</sub>	
	Pt100, Pt200, Pt500, Pt1000, Pt2000 and resistance via MSI-V-RTD  -200° C to 1000° C and 8 to 4 kΩ					

2

# HSI-STG Isolated universal input module

■ Strain gauge, bridge sensors: ±0.1 to ±1000 mV/V (@ 5 V<sub>DC</sub> excitation)
■ Piezoresistive bridge: ±0.5 to ±10000 mV/mA (@ 1 mA excitation)

■ Voltage input: ±500 µV to ±10 V

■ RTD Resistance Temperature Detector (Pt100 to Pt1000)

9 resistance ranges (8 to 4000 Ω)

Resistance: 25 mΩ to 100 kΩ

■ Isolation: 350 V<sub>pc</sub>

■ Signal connection: 9-pin SUB-D socket

#### Additional signal input using MSI

■ IEPE® Constant current powered sensors (accelerometers,

microphones); 12 ranges (±100 mV to 10 V);

requires MSI-BR-ACC

■ THERMOCOUPLE full range of TC type

requires MSI-BR-TH-x

■ CHARGE Charge up to 50000 pC

requires MSI-BR-CH-50

■ VOLTAGE up to ±200 V

requires MSI-BR-V-200

#### Module specifications

	HSI-STG					
Gain	0.5 to 10 000; free programmable					
Voltage input ranges Sensitivity @ 5 V <sub>DC</sub> excitation	$\pm 0.5^3$ , $\pm 1^3$ , $\pm 2.5^3$ , $\pm 5$ , $\pm 10$ , $\pm 25$ , $\pm 50$ , $\pm 100$ , $\pm 250$ , $\pm 500$ mV, $\pm 1$ V, $\pm 2$ V, $\pm 5$ V, $\pm 10$ V <sup>3</sup> $\pm 0.1^3$ , $\pm 0.2^3$ , $\pm 0.5^3$ , $\pm 1$ , $\pm 2$ , $\pm 5$ , $\pm 10$ , $\pm 20$ , $\pm 50$ , $\pm 100$ , $\pm 200$ , $\pm 400$ , $\pm 1000$ mV/V					
Resistance	25 m $\Omega$ to 100 k $\Omega$					
Input impedance	>100 M $\Omega$ (power off: 50 k $\Omega$ )					
Input noise	7 nV * √Hz					
Voltage input 1 year accuracy <sup>1)</sup> Gain drift Offset drift linearity	$\pm 0.05$ % of reading $\pm$ 0.02 % of range $\pm 10~\mu V$ typical 10 ppm/°K max. 20 ppm/°K typical 0.3 $\mu V/^{\circ} K$ + 5 ppm of range/°K, max 2 $\mu V/^{\circ} K$ + 10 ppm of range typical 0.03 %					
Input coupling	DC or AC (-3 dB @ 1 Hz); max. DC voltage when AC coupled: 35 V					
Excitation voltage  1 year accuracy¹)  Drift  Current limit  Protection	0, 0.25, 0.5, 1, 2.5, 5,10 and 12 $V_{_{DC}}$ software programmable (16 Bit DAC) $\pm 0.03~\% \pm 1~mV$ $\pm 10~ppm/°K \pm 50~\mu V/°K$ 100 mA Continuous short to ground					
Excitation current 1 year accuracy¹)  Compliance voltage Output impedance	0.1, 0.2, 0.5, 1, 2, 5, 10 and 20 mA software programmable (16 Bit DAC) 0.1 mA to 5 mA: 0.05% ±0.5 μA typical 15 ppm/°C >5 mA to 60 mA: 0.3% ±20 μA typical 100 ppm/°C 12 V >1 MOhm					
Supported sensors	4- or 6-wire full bridge 3- or 5-wire ½ bridge with internal completion (software programmable) 3- or 4-wire ½ bridge with internal resistor for 120 and 350 Ohm (software programmable)¹¹ 4-wire full bridge with constant current excitation (piezoresistive bridge sensors) Potentiometric Resistance Resistance Temperature Detection with Software linearization: Pt100, Pt200, Pt500, Pt1000					
Bridge resistance	80 Ω to 10 kΩ @ $\leq$ 5 V <sub>DC</sub> excitation					
Shunt calibration	Two internal shunt resistors 59.88 kOhm and 175 kOhm					
Shunt and completion resistor accuracy	0.05 % ±15 ppm/°K					
Automatic bridge balance	Input range 500 μV to 25 mV: ±400 % of Range >25 mV to 10 V : ±200% of Range, or limited by input range to maximum ±10 V					
Bandwidth <sup>2)</sup> (-3 dB)	5 mV to 5V input range: 2 MHz; 500 μV: 1 MHz; 1 mV: 1.5 MHz, 2.5 mV 1.9 Mhz, 10 V: 1 MHz					
Filters (low pass)	100 Hz, 300 Hz, 1 kHz, 3 kHz, 10 kHz, 30 kHz, 100 kHz, 300 kHz, 1 MHz (±1.5 dB @ f <sub>0</sub> )					
Filter characteristics	100 Hz to 1 MHz: Butterworth or Bessel 40 dB/dec (2 <sup>nd</sup> order; ±1.5 dB @ f <sub>0</sub> ) 2 MHz: Butterworth 60 dB/dec (3 <sup>nd</sup> order; 0 to -3 dB @ 2 MHz)					
Signal delay @ 2 MHz bandwidth	450 nsec					

continued on next page



HSI-STG-D

Rise time @ 2 MHz bandwidth	≥ 200 nsec							
Typical THD	95 dB, 1 KHz input signal at 1 V range							
Typical SFDR and SNR	1 kHz bandwidth SFDR SNR			100 kHz bandwidth SFDR SNR		1 MHz bandwidth SFDR SNR		
1 mV	80 dB 66 dB	80 dB	62 dB	80 dB	55 dB	47 dB	46 dB	
100 mV	100 dB 82 dB	90 dB	78 dB	90 dB	71 dB	66 dB	60 dB	
1000 mV	110 dB 100 dB	110 dB	97 dB	106 dB	91 dB	87 dB	79 dB	
Typical CMRR 50Hz 1kHz 10kHz 100kHz	0.5mV to 1V range 160 dB 126 dB 104 dB 87 dB	2V to 10V 160 dB 105 dB 87 dB 71 dB	range					
Isolation	±350 V <sub>pc</sub> continuous (for input, excitation and TEDS interface)							
Common mode voltage	±350 V <sub>DC</sub> continuous (for imput, excitation and TEDS interface)							
Over voltage protection	±30 V <sub>DC</sub> input (+) to input (-)							
ESD protection	IEC61000-4-2: ±8 kV air discharge, ±4 kV contact discharge							
Output voltage	±5 V							
Output resistance	10 Ω							
Output current	Max. 5 mA							
Output protection	Short to ground for 10 seconds							
RS-485 interface	Yes							
Special function	Integrated temperature sensor							
Supported TEDS chips	DS2406, DS2430A, DS2431, DS2432, DS2433							
MSI support	MSI-BR-TH-x, MSI-BR-ACC, MSI-BR-V-200, MSI-BR-CH-50							
Power supply voltage	±9 V <sub>DC</sub> (±1 %)							
Power consumption	Typ. $1.5$ W @ $350$ Ohm, $2$ W @ $120$ Ohm (both full bridge @ $5$ V $_{DC}$ excitation) Max. $3$ W (depending on sensor); overall current should not exceed DEWE-30-xx maximum power							

<sup>&</sup>lt;sup>1)</sup> Conditions fo accuracy: module temperature is calibration temperature ±5 °C; humidity is 30 % to 90 % relative humidity.

<sup>2)</sup> Please consider possible bandwidth limitation of further components in the measuring chain e.g. A/D card or signal conditioning mainframe.

<sup>&</sup>lt;sup>3)</sup> This range has limited full power bandwidth.

Isolated high voltage module HSI-HV

7 ranges ( $\pm$ 20 V to  $\pm$ 1400 V) Input ranges:

2 MHz Bandwidth:

Isolation: 1.8 kV<sub>RMS</sub> line to line

1.4 kV<sub>RMS</sub> line to ground

Input impedance: 10 MΩ

Protection: 4 kV burst, surge Signal connection: Banana sockets

### Module specifications

	HSI-HV									
nput ranges	±20 V <sup>1)</sup> , ±50 V <sup>1</sup>	, ±100	V, ±200 V, ±4	00 V, ±800	V, ±1400 V					
1 year accuracy <sup>2)</sup>	Range Signal frequency Accuracy									
	20 V; 50 V	50 V DC			±0.05 % of reading ±60 mV					
	100 V to 1400 V	/	DC				0.05 % of rar	nge		
		0.	.1Hz to 500 H	Z			0.01 % of rar			
			500 Hz to 5 kH		±0.1 % of reading ±0.05 % of range					
			kHz to 50 kH				.05 % of rang			
		>50 kHz to 100 kHz >100 kHz to 1 MHz				$\pm (0.016 \text{ f})$ % of reading $\pm 0.1$ % of range				
		>1 MHz to 2 MHz			$\pm$ (0.010*f) % of reading $\pm$ 1 % of range $\pm$ (0.014*f) % of reading $\pm$ 3 % of range					
		1 1111 2 10 2 1111 12				f = signal frequency in kHz				
Gain linearity	0.05 %									
Gain drift range	Typically 20 pp	m/°C (	max. 50 ppm/	°C)						
Offset drift	, , , , , , , ,	•		,						
20 V to 100 V	typical 1.5 mV/			x. 4 mV/°C						
200 V to 1400 V	typical 5 ppm/°			x. 20 ppm	of range/°C					
Long term stability	100 ppm/sqrt (	1000 h	rs)							
Input resistance	10 MΩ    2.2 pF									
-3 dB Bandwidth	2 MHz									
Signal delay @ full bandwidth	approx. 390 ns									
Filter selection	Push button or software									
Filter (lowpass)	100, 300, 1k, 3k, 10k, 30k, 100k, 300 kHz, 1 MHz, 2 MHz <sup>3)</sup>									
Filter type	Bessel or Butterworth 40 dB/decade									
Filter characteristics										
100 Hz to 1 MHz	Butterworth or									
2 MHz	Butterworth 60 dB/dec (3 <sup>rd</sup> order; 0 to -3 dB @ 2 MHz)									
Typical SFDR and SNR	10kHz bandwid	ith NR	100kHz ba SFDR	ndwidth SNR	1MHz ba SFDR		2 MHz ba	andwidth SNR		
50 V	1 -	vir. ∣dB	110 dB	82 dB	94 dB	SNR 76 dB	84 dB	73 dB		
400 V		dB dB	110 dB	92 dB	94 dB	82 dB	84 dB	77 dB		
1400 V		dB	110 dB	95 dB	94 dB	82 dB	84 dB	77 dB		
Typical CMRR	>80 dB @ 50 H	lz	60 dB @ 1	kHz						
•	70 dB @ 400 H		48 dB @ 1	0 kHz						
Isolation voltage	Line to Ground									
	Line to Line 1.8	kVrm	S							
Protection	CAT III 600									
Surgo (1.2/50)	CAT IV 300 ±4000 V									
Surge (1.2/50) Burst (5 kHz)	±4000 V									
Output voltage	±5 V									
Output resistance	10 Ohm									
Output current maximum	35 mA	CALI	ΓΙΟΝ: do not e	exceed man	kimum outpi	ıt current!				
Power supply	±9 V <sub>DC</sub> ± 1%	<i>0,</i> 10	511. 30 1100		outpt					
Power consumption	1.2 W									
Power On default settings		amahla	۷							
Special functions	Software programable Integrated temperature sensor									
Programming interface	RS-485	Joralui	0 3611301							
rogramming interface	110-400									

<sup>20</sup> V and 50 V are auxiliary ranges and have a limited bandwidth.

<sup>20</sup> V range typically 0.9 Mhz 50 V range typically 1.9 Mhz

<sup>&</sup>lt;sup>2)</sup> Conditions for accuracy: Module temperature is calibration temperature ±5 °C; humidity is 30 to 90 RH;

AC accuracy: the highest filter (2 Mhz) has to be activated. f = signal frequency in kHz.

for the 2 year accuarcy multiply all % of range and % of reading values by 1.5.

<sup>(3) 2</sup> MHz filter: exclusively Butterworth 60 dB/decade. Please consider possible bandwidth limitation of further components in the measuring chain, e.g. A/D cards or signal conditioning mainframe

HSI-LV Isolated low voltage module

Voltage input: 12 ranges (10 mV to 50 V)
 Current input: ±20 mA using SE-CUR-SHUNT-1

±5 A using SE-CUR-SHUNT-4 or -SHUNT-5

■ Bandwidth: 2 MHz

Additional signal input using MSI

■ IEPE® Constant current powered sensors

(accelerometers, microphones); 12 ranges

(10 mV to 5 V); requires MSI-V-ACC

■ RTD Resistance Temperature Detector (Pt100 to Pt2000)

9 resistance ranges (8 to 4000  $\Omega$ );

requires MSI-V-RTD



HSI-LV-LEMO HSI-LV-BNC

HSI-LV-B

#### Module specifications

	HSI-LV							
Input ranges	10 mV, 20 mV, 50 mV, 100 mV, 200 mV, 500 mV, 1 V, 2.5 V, 5 V, 10 V, 25 V, 50 V							
Button selectable ranges	10 mV, 50 mV, 200 mV, 1 V, 5 V, 10 V, 50 V							
Rated input voltage	33 $V_{RMS}$ , 46.7 $V_{PEAK}$ , 70 $V_{DC}$ according to EN-61010-1 and EN-61010-2-30							
l year accuracy <sup>1)</sup>	Range	I LAK	Signal frequ		Accuracy			
Bipolar	10 mV to 100	mV	DC	_	±0.02 %	of reading ±6	0 μV	
	2.5 V	2.5 V DC ±0.02 % of reading ±0.1 % of range						е
	200 mV to 50							
	10 mV to 100	mV	>5 kHz to 5 >50 kHz to >100 kHz to	0.1 Hz to 5 kHz				range nge
	200 mV to 50	V	0.1 Hz to 5 >500 Hz to >5 kHz to 5 >50 kHz to >100 kHz to >1 MHz to	5 kHz 60 kHz 100 kHz o 1 MHz	±0.1 % of ±0.4 % of ±(0.016*f ±(0.010*f ±(0.014*f	of reading ±0.0 freading ±0.0 freading ±0.0 freading ±0.0 () % of readin () %	05 % of rang 05 % of rang g ±0.1 % of g ±1 % of ra g ±3 % of ra	e e range nge
Unipolar	10 mV to 100 200 mV to 50		DC DC			of reading ±6 of reading ±0		ge
nput coupling	DC or AC software selectable (1.5 Hz standard, custom on request down to 0.01 Hz)							
Sain linearity	Typically 0.01	%; max	. 0.04 % of fu	II scale				
Gain drift range	Typically 10 ppm/°C (max. 30 ppm/°C)							
Offset drift	10 mV to 200 mV: Typically 3 μV/°C 500 mV to 50 V: Typically 10 ppm of range/°C							
ong term stability	100 ppm/sqrt (1000 hrs)							
nput resistance	1 MOhm							
Bandwidth (-3 dB)	2 MHz							
Signal delay @ full bandwidth	approx. 405 ns							
Filter selection	Push button or software							
ilter	100 Hz, 300 Hz, 1 kHz, 3 kHz, 10 kHz, 30 kHz, 100 kHz, 300 kHz, 1 MHz, 2 MHz <sup>2)</sup>							
Filter type	Bessel or Butterworth 40 dB/dec							
Filter characteristics 100 Hz to 1 MHz 2 MHz	Butterworth or Bessel 40 dB/dec (2 <sup>nd</sup> order; ±1.5 dB @ f <sub>0</sub> ) Butterworth 60 dB/dec (3 <sup>rd</sup> order; 0 to -3 dB @ 2 MHz)							
Гурісаl SFDR and SNR:	10 kHz bandw SFDR	idth SNR	100 kHz ba SFDR	andwidth SNR	1 MHz b SFDR	andwidth SNR	2 MHz ba SFDR	andwidth SNR
20 mV		78 dB	88 dB	71 dB	77 dB	60 dB	76 dB	56 dB
1 V		98 dB	110 dB	95 dB	93 dB	82 dB	84 dB	75 dB
50 V		98 dB	110 dB	95 dB	94 dB	82 dB	85 dB	75 dB
Typical CMRR	10 mV to 1 V r	ange:	2.5 V to 50 100 dB	v range:				
50 Hz 1 kHz	130 dB 120 dB		100 dB					
10 kHz	95 dB		40 dB					
100 kHz	75 dB		40 dB 20 dB					
continued on next page	10 ab		20 GD					

#### continued from previous page

Input overvoltage protection	350 V <sub>DC</sub>
Isolation voltage	1 kV <sub>RMS</sub> <sup>3)</sup>
Sensor supply	±9 V (±1 %), 12 V (±5 %), 200 mA resettable fuse protected <sup>4)</sup>
Output voltage	±5 V
Output resistance	10 Ohm
Maximum output current	5 mA
Output protection	Short to ground for 10 sec.
Power On default settings	Software programable
Power supply	±9 V <sub>DC</sub> ±1 %
Power consumption	1.1 W without sensor supply
Special functions	Integrated temperature sensor
RS-485 interface	Yes
TEDS	Hardware support for TEDS (Transducer Electronic Data Sheet)
Supported TEDS chips	DS2406, DS2430A, DS2432, DS2433, DS2431
Supported MSI	MSI-V-ACC, MSI-V-RTD

<sup>1)</sup> Conditions for accuracy: Module temperature is calibration temperature ±5 °C; humidity is 30 to 90 RH.

AC accuracy: the highest filter (2 MHz) has to be activated. f = signal frequency in kHz.

For the 2 year accuracy multiply all % of range and % of reading values by 1.5.

<sup>&</sup>lt;sup>2)</sup> 2 MHz filter: exclusively for Butterworth 60 dB/decade - refer to filter specifications. Please consider possible bandwidth limitation of further components in the measuring chain, e.g. A/D card or signal conditioning mainframe.

<sup>3)</sup> Although the rated input voltage is 33 V<sub>RMS</sub>, 46.7 V<sub>PEAK</sub> or 70 V<sub>DC</sub> according to EN-61010-1 and EN-61010-2-30, the galvanic isolation has been tested with 1 kV<sub>RMS</sub> for 1 min.

<sup>4)</sup> Overall current should not exceed DEWE-30-xx maximum power.